## NSN 5962-01-028-2081

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Body	Len	gth:
D - 4	0	745

Between 0.745 inches and 0.785 inches

**Body Width:** 

Between 0.240 inches and 0.260 inches

**Body Height:** 

Between 0.095 inches and 0.140 inches

**Maximum Power Dissipation Rating:** 

500.0 milliwatts

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### **Storage Tempurature Range:**

-65.0/+150.0 degrees celsius

### **End Application:**

Receiver fscm 50464

#### **Features Provided:**

Hermetically sealed and monolithic and high voltage and positive outputs and edge triggered and w/clear and resettable and w/enable

## **Inclosure Material:**

Ceramic and glass

## **Inclosure Configuration:**

Dual-in-line

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

Dual 3 input

## **Case Outline Source And Designator:**

-0-001-ae joint electron device engineering council

## **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 20.5 volts power source

## **Memory Device Type:**

Rom

## **Test Data Document:**

81349-mil-std-883 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

16 printed circuit

## Shelf Life:

N/a

#### **Unit Of Measure:**

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#### **Demilitarization:**

Yes - demil/mli

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